

# Yixiu Wang

## List of Publications by Year in descending order

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Version: 2024-02-01

30  
papers

2,400  
citations

331670

21  
h-index

580821

25  
g-index

30  
all docs

30  
docs citations

30  
times ranked

2550  
citing authors

#	ARTICLE	IF	CITATIONS
1	Field-effect transistors made from solution-grown two-dimensional tellurene. <i>Nature Electronics</i> , 2018, 1, 228-236.	26.0	591
2	One-Dimensional van der Waals Material Tellurium: Raman Spectroscopy under Strain and Magneto-Transport. <i>Nano Letters</i> , 2017, 17, 3965-3973.	9.1	272
3	Stable mid-infrared polarization imaging based on quasi-2D tellurium at room temperature. <i>Nature Communications</i> , 2020, 11, 2308.	12.8	259
4	Tellurene: its physical properties, scalable nanomanufacturing, and device applications. <i>Chemical Society Reviews</i> , 2018, 47, 7203-7212.	38.1	214
5	Raman response and transport properties of tellurium atomic chains encapsulated in nanotubes. <i>Nature Electronics</i> , 2020, 3, 141-147.	26.0	126
6	Tellurene Photodetector with High Gain and Wide Bandwidth. <i>ACS Nano</i> , 2020, 14, 303-310.	14.6	101
7	Large-Area Direct Laser-Shock Imprinting of a 3D Biomimic Hierarchical Metal Surface for Triboelectric Nanogenerators. <i>Advanced Materials</i> , 2018, 30, 1705840.	21.0	93
8	Thermoelectric Performance of 2D Tellurium with Accumulation Contacts. <i>Nano Letters</i> , 2019, 19, 1955-1962.	9.1	81
9	Solution-synthesized chiral piezoelectric selenium nanowires for wearable self-powered human-integrated monitoring. <i>Nano Energy</i> , 2019, 56, 693-699.	16.0	71
10	Quantum Hall effect of Weyl fermions in n-type semiconducting tellurene. <i>Nature Nanotechnology</i> , 2020, 15, 585-591.	31.5	63
11	Quantum Transport and Band Structure Evolution under High Magnetic Field in Few-Layer Tellurene. <i>Nano Letters</i> , 2018, 18, 5760-5767.	9.1	60
12	Tellurene: A Multifunctional Material for Midinfrared Optoelectronics. <i>ACS Photonics</i> , 2019, 6, 1632-1638.	6.6	60
13	Wearable high-dielectric-constant polymers with core-shell liquid metal inclusions for biomechanical energy harvesting and a self-powered user interface. <i>Journal of Materials Chemistry A</i> , 2019, 7, 7109-7117.	10.3	48
14	Chitosan biopolymer-derived self-powered triboelectric sensor with optimized performance through molecular surface engineering and data-driven learning. <i>Informa Mater</i> , 2019, 1, 116-125.	17.3	47
15	Data-driven and probabilistic learning of the process-structure-property relationship in solution-grown tellurene for optimized nanomanufacturing of high-performance nanoelectronics. <i>Nano Energy</i> , 2019, 57, 480-491.	16.0	44
16	Strain-Engineered Anisotropic Optical and Electrical Properties in 2D Chiral Chain Tellurium. <i>Advanced Materials</i> , 2020, 32, e2002342.	21.0	40
17	Anisotropic thermal conductivity in 2D tellurium. <i>2D Materials</i> , 2020, 7, 015008.	4.4	39
18	The resurrection of tellurium as an elemental two-dimensional semiconductor. <i>Npj 2D Materials and Applications</i> , 2022, 6, .	7.9	36

#	ARTICLE	IF	CITATIONS
19	Piezotronic effect in 1D van der Waals solid of elemental tellurium nanobelt for smart adaptive electronics. <i>Semiconductor Science and Technology</i> , 2017, 32, 104004.	2.0	32
20	Imaging Carrier Inhomogeneities in Ambipolar Tellurene Field Effect Transistors. <i>Nano Letters</i> , 2019, 19, 1289-1294.	9.1	31
21	Gate-tunable strong spin-orbit interaction in two-dimensional tellurium probed by weak antilocalization. <i>Physical Review B</i> , 2020, 101, .	3.2	29
22	High-Performance Few-Layer Tellurium CMOS Devices Enabled by Atomic Layer Deposited Dielectric Doping Technique. , 2018, , .		16
23	Scalable nanomanufacturing and assembly of chiral-chain piezoelectric tellurium nanowires for wearable self-powered cardiovascular monitoring. <i>Nano Futures</i> , 2019, 3, 011001.	2.2	16
24	Infrared ultrafast spectroscopy of solution-grown thin film tellurium. <i>Physical Review B</i> , 2019, 100, .	3.2	13
25	Parallel Nanoimprint Forming of One-Dimensional Chiral Semiconductor for Strain-Engineered Optical Properties. <i>Nano-Micro Letters</i> , 2020, 12, 160.	27.0	8
26	Bilayer Quantum Hall States in an n-Type Wide Tellurium Quantum Well. <i>Nano Letters</i> , 2021, 21, 7527-7533.	9.1	6
27	Wafer-scale Material-device Correlation of Tellurene MOSFETs. , 2018, , .		2
28	Selenene and Tellurene. , 2022, , 197-224.		2
29	Microscopic origin of inhomogeneous transport in four-terminal tellurene devices. <i>Applied Physics Letters</i> , 2020, 117, .	3.3	0
30	High-Frequency Tellurene MOSFETs with Biased Contacts. , 2021, , .		0